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Intel, Micron claim first for 50 nano flash

IM FLASH TECHNOLOGIES, a joint venture between Micron and Intel, said they've produced the first NAND flash memory using 50 nanometre process technology. IM is sampling four gigabit devices and mass production isn't likely until next year. The samples are from Micron's Boise and Manassas fabs. A factory in Lehi Utah dedicated to the joint venture will start production of NAND in the beginning of next year. Source: The Inquirer

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